# imall

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# ISOTOP<sup>®</sup> Buck chopper NPT IGBT

## $V_{CES} = 600V$ $I_{C} = 50A$ @ Tc = 90°C

### Application

- AC and DC motor control
- Switched Mode Power Supplies

### Features

- Non Punch Through (NPT) THUNDERBOLT IGBT
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 100 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- ISOTOP<sup>®</sup> Package (SOT-227)
- Very low stray inductance
- High level of integration

### Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive  $T_C$  of  $V_{CEsat}$
- RoHS Compliant

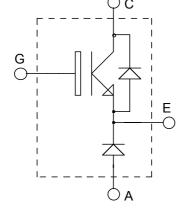
### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V <sub>CES</sub>	Collector - Emitter Breakdown Voltage		600	V
I <sub>C1</sub>	Continuous Collector Current	$T_C = 25^{\circ}C$	75	
I <sub>C2</sub>	T <sub>C</sub> =		50	А
I <sub>CM</sub>	Pulsed Collector Current	$T_C = 25^{\circ}C$	160	
V <sub>GE</sub>	Gate – Emitter Voltage		±20	V
$P_D$	Maximum Power Dissipation	$T_C = 25^{\circ}C$	277	W
$I_{LM}$	RBSOA clamped Inductive load Current $R_G=11\Omega$		100	А
IF <sub>AV</sub>	Maximum Average Forward Current Duty cycle=0.5	$T_C = 80^{\circ}C$	30	А
IF <sub>RMS</sub>	RMS Forward Current (Square wave, 50% duty)		39	Л

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

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### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
т	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25^{\circ}C$			40	μA
I <sub>CES</sub>	Zero Gate Voltage Collector Current	$V_{CE} = 600 V$	$T_{j} = 125^{\circ}C$			1000	μA
V <sub>CE(sat)</sub>	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		2.1	2.7	V
		$I_{\rm C} = 50 {\rm A}$ $T_{\rm j} = 125$	$T_{j} = 125^{\circ}C$		2.2	2.8	v
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 700 \mu A$		4.5	5.5	6.5	V
I <sub>GES</sub>	Gate – Emitter Leakage Current	$V_{GE} = \pm 20V, V_{CE} = 0V$				±100	nA

### **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$		2250		
C <sub>oes</sub>	Output Capacitance	$V_{CE} = 25V$		255		pF
C <sub>res</sub>	Reverse Transfer Capacitance	f = 1 MHz		155		
Qg	Total gate Charge	$V_{GS} = 15V$		175		
Q <sub>ge</sub>	Gate – Emitter Charge	$V_{Bus} = 300V$		18		nC
Q <sub>gc</sub>	Gate – Collector Charge	$I_C = 50A$		100		
T <sub>d(on)</sub>	Turn-on Delay Time	Resistive Switching (25°C)		29		ns
Tr	Rise Time	$V_{GE} = 15V$ $V_{Bus} = 300V$		118		
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 500 V$ $I_C = 50 A$		150		
T <sub>f</sub>	Fall Time	$R_G = 10\Omega$		190		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (25°C)		30		ns
Tr	Rise Time	$V_{GE} = 15V$		80		
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 400V$ $I_C = 50A$		240		
T <sub>f</sub>	Fall Time	$\frac{R_{\rm C} = 30 \Lambda}{R_{\rm G} = 10 \Omega}$		43		
Ets	Total switching Losses			3.6		mJ
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (150°C)		28		
Tr	Rise Time	$V_{GE} = 15V$		75		
T <sub>d(off)</sub>	Turn-off Delay Time	$V_{Bus} = 400V$ $I_{C} = 50A$ $R_{G} = 10\Omega$		265		ns
T <sub>f</sub>	Fall Time			185		
Eon	Turn-on Switching Energy			1.8		
E <sub>off</sub>	Turn-off Switching Energy			2.4		mJ
E <sub>ts</sub>	Total switching Losses			4.2		



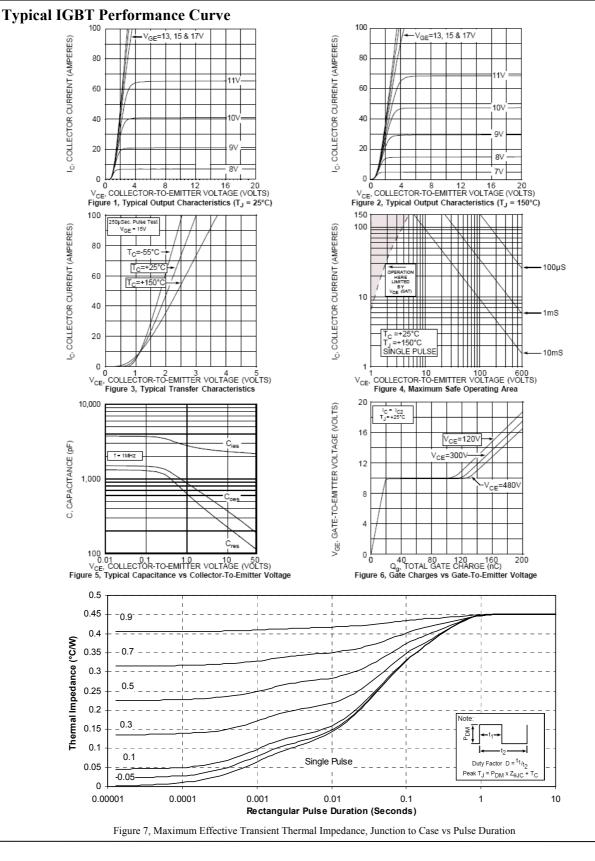
### Chopper diode ratings and characteristics

Symbol	Characteristic	<b>Test</b> Conditions		Min	Тур	Max	Unit
	Diode Forward Voltage	$I_F = 30A$			1.6	1.8	
$V_{\rm F}$		$I_F = 60A$			1.9		V
		$I_F = 30A$	$T_{i} = 125^{\circ}C$		1.4		
I <sub>RM</sub>	Maximum Reverse Leakage Current	$V_{R} = 600 V$	$T_j = 25^{\circ}C$			250	μA
IRM		$V_{R} = 600 V$	$T_{j} = 125^{\circ}C$			500	μΛ
CT	Junction Capacitance	$V_{R} = 200 V$			44		pF
4	Reverse Recovery Time	$I_F=1A, V_R=30V$ di/dt =100A/µs	$T_j = 25^{\circ}C$		23		
t <sub>rr</sub>	Reverse Recovery Time	$T_i = 25^{\circ}C$ $T_i = 125^{\circ}C$	$T_i = 25^{\circ}C$		85		ns
				160			
I <sub>RRM</sub>	Maximum Reverse Recovery Current	$I_{\rm F} = 30 \text{A}$ $V_{\rm R} = 400 \text{V}$	$T_j = 25^{\circ}C$		4		А
IRRM	Maximum Reverse Recovery Current		$T_{i} = 125^{\circ}C$		8		Л
0	Paulana Pagayany Changa	$di/dt = 200 A/\mu s$	$T_j = 25^{\circ}C$		130		nC
Q <sub>rr</sub>	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		700		IIC
t <sub>rr</sub>	Reverse Recovery Time	$I_F = 30A$ $V_R = 400V$ $di/dt = 1000A/\mu s$			70		ns
Q <sub>rr</sub>	Reverse Recovery Charge		$T_{j} = 125^{\circ}C$		1300		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current				30		Α

### Thermal and package characteristics

Symbol	Characteristic		Min	Тур	Max	Unit	
R <sub>thJC</sub>	Junction to Case Thermal Resistance	IGBT			0.45		
<b>R</b> <sub>thJC</sub>		Diode			1.21	°C/W	
R <sub>thJA</sub>	Junction to Ambient (IGBT & Diode)				20		
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		2500			V	
$T_J, T_{STG}$	Storage Temperature Range		-55		150	°C	
T <sub>L</sub>	Max Lead Temp for Soldering:0.063" from case for 10 sec				300	7 C	
Torque	Mounting torque (Mounting = 8-32 or 4mm Machine and terminals = 4mm Machine)				1.5	N.m	
Wt	Package Weight			29.2		g	



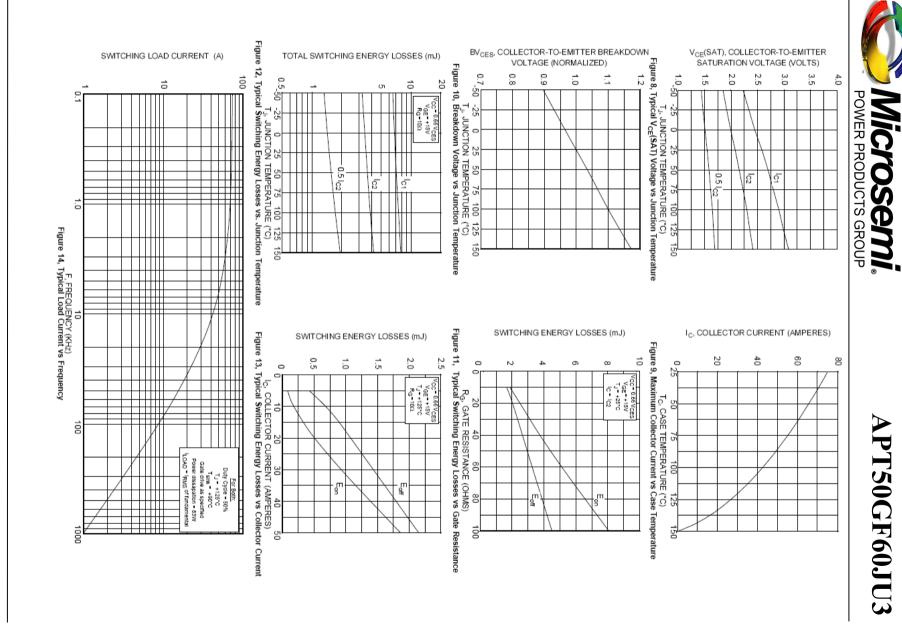


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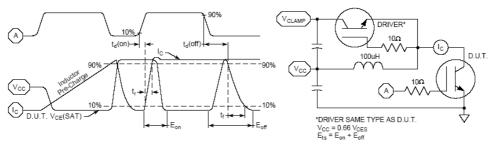


Figure 16, Switching Loss Test Circuit and Waveforms

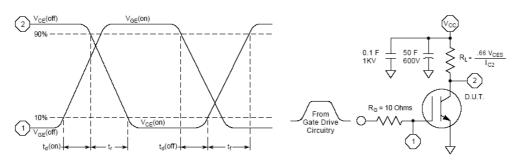
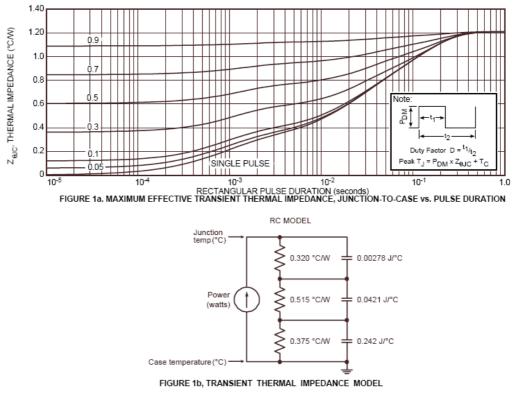


Figure 17, Resistive Switching Time Test Circuit and Waveforms

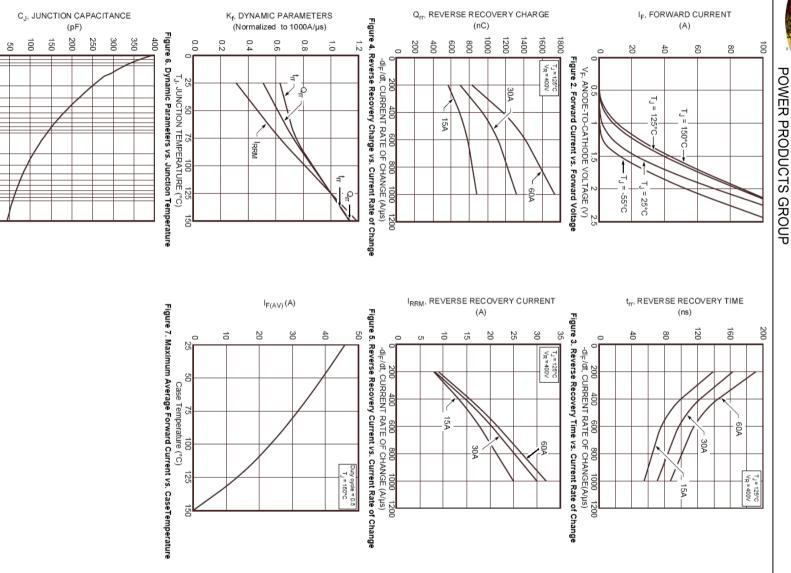
### **Typical Diode Performance Curve**



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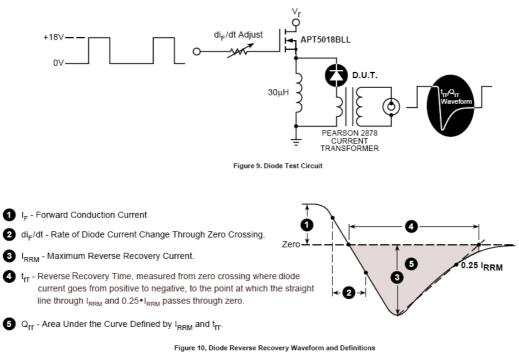
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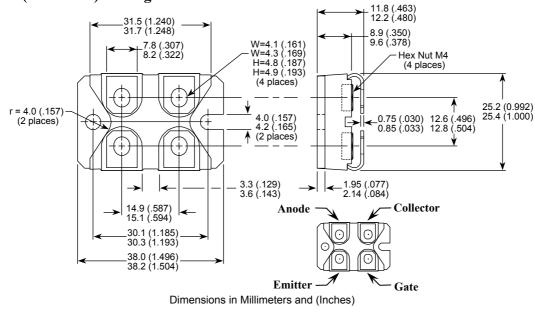
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### SOT-227 (ISOTOP<sup>®</sup>) Package Outline



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